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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR **2SK3813**

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The 2SK3813 is N-channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

• Super low on-state resistance

RDS(on)1 = $5.3 \text{ m}\Omega$ MAX. (VGS = 10 V, ID = 30 A)

 $R_{DS(on)2} = 7.1 \text{ m}\Omega \text{ MAX.} \text{ (Vgs} = 4.5 \text{ V, Id} = 30 \text{ A)}$

• Low Ciss: Ciss = 5500 pF TYP.

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3813	TO-251 (MP-3)
2SK3813-Z	TO-252 (MP-3Z)

(TO-251)



ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vgs = 0 V)	VDSS	40	V
Gate to Source Voltage (Vps = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	I _{D(DC)}	±60	Α
Drain Current (pulse) Note1	ID(pulse)	±240	Α
Total Power Dissipation (Tc = 25°C)	P _{T1}	84	W
Total Power Dissipation (T _A = 25°C)	P _{T2}	1.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C
Single Avalanche Energy Note2	Eas	137	mJ
Repetitive Avalanche Current Note3	Iar	37	Α
Repetitive Avalanche Energy Note3	Ear	137	mJ

(TO-252)



Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting T_{ch} = 25°C, V_{DD} = 20 V, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V, L = 100 μ H

3. Tch(peak) \leq 150°C, Rg = 25 Ω

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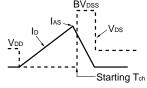
ELECTRICAL CHARACTERISTICS (TA = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 40 V, V _{GS} = 0 V			10	μА
Gate Leakage Current	Igss	Vgs = ±20 V, Vps = 0 V			±100	nA
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.5	2.0	2.5	V
Forward Transfer Admittance Note	yfs	V _{DS} = 10 V, I _D = 30 A	21	42		S
Drain to Source On-state Resistance Note	R _{DS(on)1}	Vgs = 10 V, Ip = 30 A		4.2	5.3	mΩ
	R _{DS(on)2}	Vgs = 4.5 V, ID = 30 A		5.3	7.1	mΩ
Input Capacitance	Ciss	V _{DS} = 10 V		5500		pF
Output Capacitance	Coss	V _G s = 0 V		740		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		490		pF
Turn-on Delay Time	td(on)	VDD = 20 V, ID = 30 A		25		ns
Rise Time	tr	Vgs = 10 V		8.5		ns
Turn-off Delay Time	td(off)	$R_G = 0 \Omega$		81		ns
Fall Time	t _f			10		ns
Total Gate Charge	Q _G	VDD = 32 V		96		nC
Gate to Source Charge	Qgs	V _G S = 10 V		18		nC
Gate to Drain Charge	Q _{GD}	ID = 60 A		23.5		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	IF = 60 A, Vgs = 0 V		0.94	1.5	V
Reverse Recovery Time	trr	IF = 60 A, VGS = 0 V		35		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		31		nC

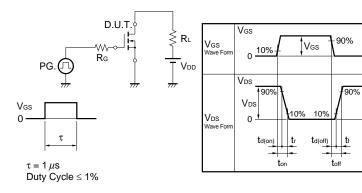
Note Pulsed

TEST CIRCUIT 1 AVALANCHE CAPABILITY

$\begin{array}{c} \text{D.U.T.} \\ \text{Rg} = 25 \ \Omega \\ \text{VGS} = 20 \rightarrow 0 \ \text{V} \end{array} \begin{array}{c} \text{D.U.T.} \\ \text{Rg} \\ \text{So} \\ \text{M} \end{array} \begin{array}{c} \text{D.U.T.} \\ \text{N} \\ \text{M} \end{array}$



TEST CIRCUIT 2 SWITCHING TIME

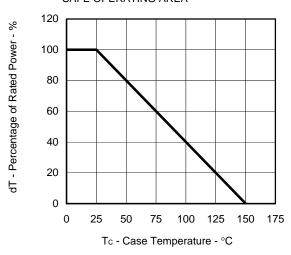


TEST CIRCUIT 3 GATE CHARGE

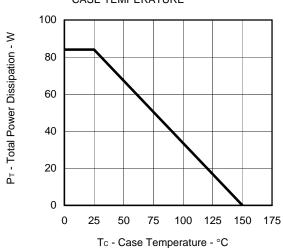
$$\begin{array}{c|c} D.U.T. \\ I_G = 2 \stackrel{m}{\text{M}} \\ \hline \\ PG. \\ \end{array} \begin{array}{c} S \\ 50 \\ \Omega \\ \end{array} \begin{array}{c} RL \\ \hline \\ V_{DD} \\ \end{array}$$

TYPICAL CHARACTERISTICS (TA = 25°C)

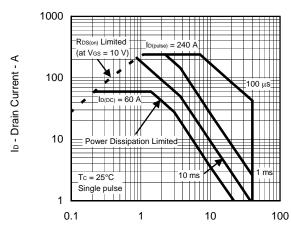
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



TOTAL POWER DISSIPATION vs. CASE TEMPERATURE

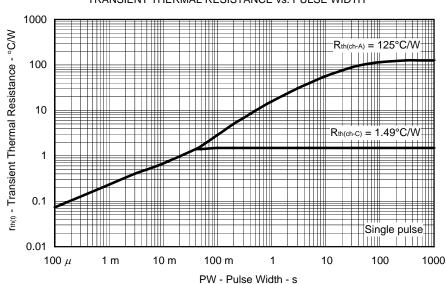


FORWARD BIAS SAFE OPERATING AREA



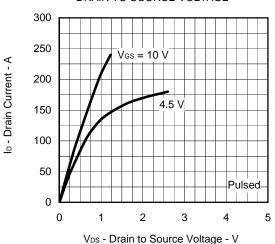
V_{DS} - Drain to Source Voltage - V

TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

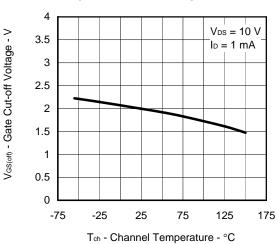


3

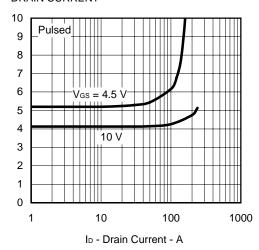
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



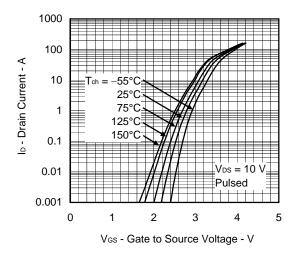
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



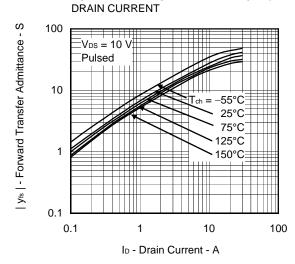
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



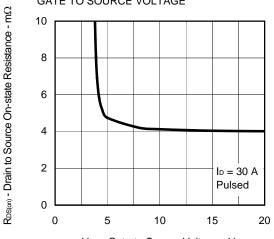
FORWARD TRANSFER CHARACTERISTICS



FORWARD TRANSFER ADMITTANCE vs.



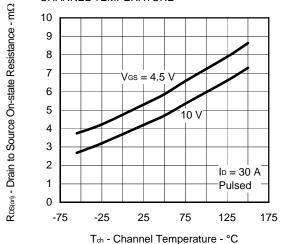
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



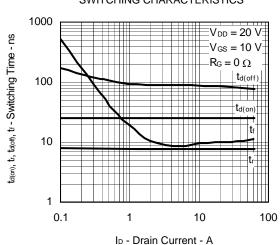
V_{GS} - Gate to Source Voltage - V

RDS(m) - Drain to Source On-state Resistance - mΩ

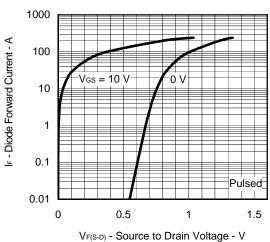
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



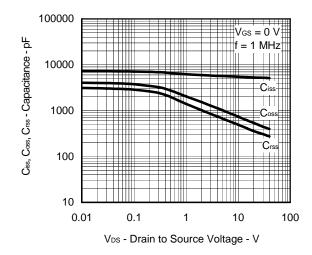
SWITCHING CHARACTERISTICS



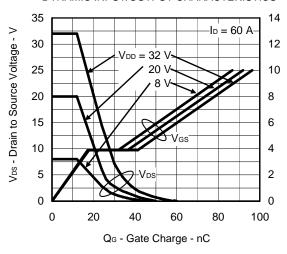
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



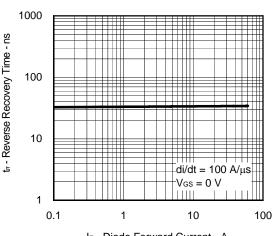
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



DYNAMIC INPUT/OUTPUT CHARACTERISTICS

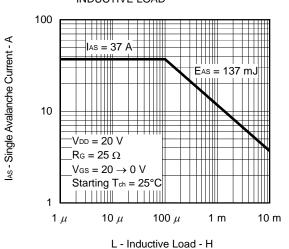


REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT

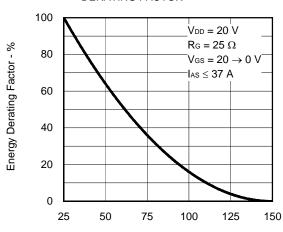


IF - Diode Forward Current - A

SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD

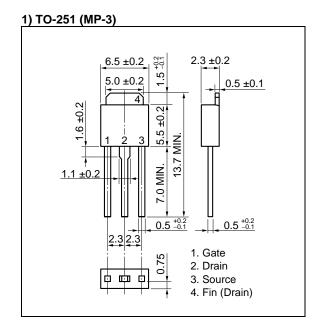


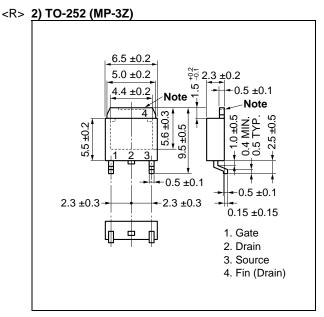
SINGLE AVALANCHE ENERGY DERATING FACTOR



Starting T_{ch} - Starting Channel Temperature - $^{\circ}C$

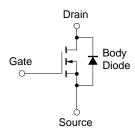
PACKAGE DRAWINGS (Unit: mm)





Note The depth of notch at the top of the fin is from 0 to 0.2 mm.

EQUIVALENT CIRCUIT



Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

Data Sheet D16739EJ3V0DS 7

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